

Application of Diamond and Sapphire Sensors at FLASH: First Results

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FLASH overview



High-gain Free Electron Laser VUV and soft X-ray regime Self-Amplified Spontaneous Emission (SASE) mode

1GeV maximum electron beam energy

Wavelength down to 6.5 nm 10 fs pulses Peak current 1-2 kA

BHM system



Sensors

- pCVD diamond produced by Diamond Detectors Ltd. Dimensions 10×10×0.3 mm³ Metallization: 50/50/200 nm Ti/Pt/Au
- Single crystal sapphire (Al₂O₃) produced by CRYSTAL GmbH Dimensions 10×10×0.5 mm³ Metallization: 50/50/200 nm Al/Ti/Au

The sensors will be operated like solid-state ionization chambers

System description



Bias voltage feed and signal readout



9 mA run



Analog signals from a diamond (left) and a sapphire (right) as a response to 1 bunch No amplification



Analog signal, bunch repetition rate 3 MHz



Signals from the BHM sensors (digital, 1 train of 30 bunches)



Signal size (V) as a function of beam position (by air BPM). Beam steering period of ~ 20 min, sweeping



Signals from the BHM sensors (diamonds)

Signals from the BHM sensors (sapphires)



Train repetition rate 5 Hz

Sweeping period 1.1 s

Summary

- 1. 4 pCVD sensors and 4 artificial sapphire sensors were used for Beam Halo Monitor system at FLASH
- 2. All the sensors were operational during the test run
- 3. The dependence of the signal size on the beam position was observed
- 4. Diamond sensors were sensitive to the beam position change due to sweeping
- 5. The analysis is ongoing

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